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on semiconductor® FDMS86568-F085

N-Channel PowerTrench[®] MOSFET 60 V, 80 A, 3.5 m Ω

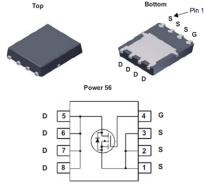
Features

- Typical $R_{DS(on)}$ = 2.6 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 55 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems





MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units V	
V _{DSS}	Drain-to-Source Voltage		60		
V _{GS}	Gate-to-Source Voltage		±20	V	
ID	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	80	•	
	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	102	mJ	
P _D	Power Dissipation		214	W	
	Derate Above 25°C		1.43	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
R _{0JC}	Thermal Resistance, Junction to Case		0.7	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, L = 50uH, $I_{AS} = 64$ A, $V_{DD} = 60$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

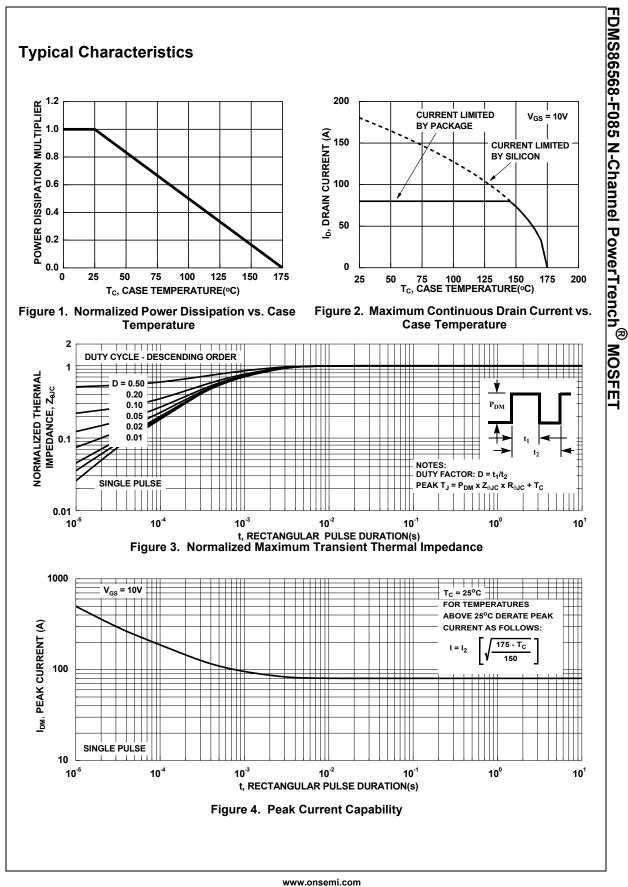
3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

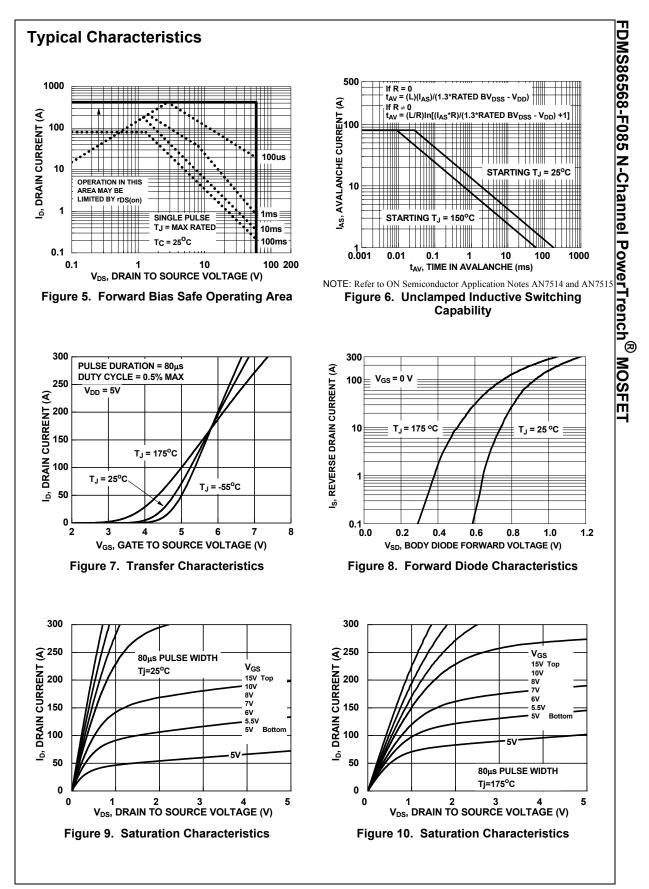
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86568	FDMS86568-F085	Power56	13"	12mm	3000units

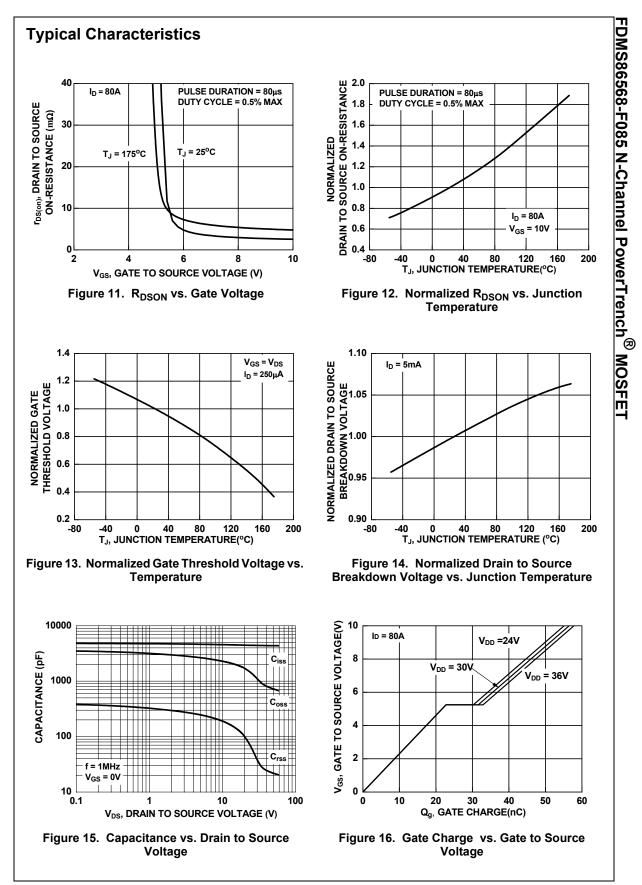
Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics							
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		60	-	-	V	
		$V_{DS} = 60V$ $T_J = 25^{\circ}C$		-	-	1	μA	
I _{DSS}	Drain-to-Source Leakage Current			C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$			-	-	±100	nA
On Cha	racteristics							
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.0	3.0	4.0	V	
		I _D = 80A,			-	2.6	3.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V		^o C (Note 4)	-	4.9	6.6	mΩ
Dynami	c Characteristics							
C _{iss}	Input Capacitance	$V_{\rm DS} = 30V, V_{\rm GS} = 0V,$		-	4335	-	pF	
C _{oss}	Output Capacitance			-	1065	-	pF	
C _{rss}	Reverse Transfer Capacitance	f = 1MHz			-	36	-	pF
Rg	Gate Resistance	f = 1MHz			-	2.5	-	Ω
Q _{g(ToT)}	Total Gate Charge	V_{GS} = 0 to 10V V_{DD} = 48V V_{GS} = 0 to 2V I_D = 80A		-	55	71	nC	
Q _{g(th)}	Threshold Gate Charge			-	8	-	nC	
Q _{gs}	Gate-to-Source Gate Charge				-	23	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge				-	9	-	nC
Switchi	ng Characteristics							
t _{on}	Turn-On Time				-	-	64	ns
t _{d(on)}	Turn-On Delay	$V_{DD} = 30V, I_D = 80A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$		-	21	-	ns	
t _r	Rise Time			-	20	-	ns	
t _{d(off)}	Turn-Off Delay			-	33	-	ns	
t _f	Fall Time			-	13	-	ns	
t _{off}	Turn-Off Time				-	-	64	ns
Drain-S	ource Diode Characteristics							
Var	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V	
V_{SD}	Source-to-brain bloce voltage	I _{SD} = 40A, V _{GS} = 0V		-	-	1.2	V	
05	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/ms V _{DD} = 48V		0A/ms	-	67	87	ns
t _{rr}	Reverse-Recovery Charge			-	70	99	nC	

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